

Supporting Information

Exploration of Photocatalytic Overall Water Splitting Mechanisms in the Z-scheme SnS₂/β-As Heterostructure

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Gibbs free energy change of HER and OER

The Gibbs free energy change ΔG of HER and OER can be calculated by the formula proposed by Nørskov¹:

$$\Delta G = \Delta E + \Delta E_{ZPE} - T\Delta S + \Delta G_U + \Delta G_{pH} \quad (1)$$

where ΔE is the reaction energy calculated by the DFT. ΔE_{ZPE} is the zero-point energy by harmonic vibrational frequency calculations. ΔS is the entropy difference between the adsorbed state and the gas phase. T is the system temperature (298.15 K). $\Delta G_U = -eU$, U is the external potential relative to the standard hydrogen electrode. ΔG_{pH} ($\Delta G_{pH} = K_B T \times \ln 10 \times \text{pH}$) represents the free energy contributed in different pH concentrations.

The equations involved in HER can be expressed as²⁻³:

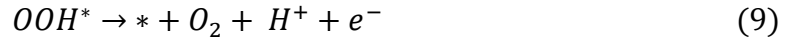
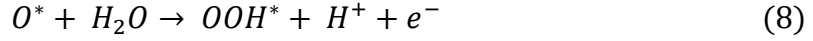
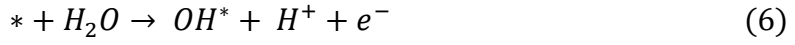


$$\Delta G_h = G(H^*) - G(*) - 0.5G(H_2) + 0.059 \times pH - eU \quad (4)$$

$$\Delta G'_h = G(*) - G(H^*) + 0.5G(H_2) + 0.059 \times pH - eU \quad (5)$$

The equations involved in OER can be expressed as:

OER-I²⁻³:



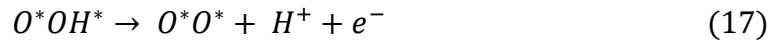
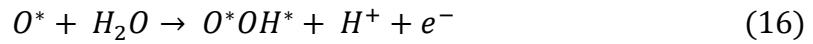
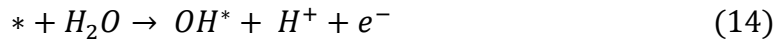
$$\Delta G_1 = G(OH^*) + 0.5G(H_2) - G(*) - G(H_2O) - 0.059 \times pH - eU \quad (10)$$

$$\Delta G_2 = G(O^*) + 0.5G(H_2) - G(OH^*) - 0.059 \times pH - eU \quad (11)$$

$$\Delta G_3 = G(OOH^*) + 0.5G(H_2) - G(O^*) - G(H_2O) - 0.059 \times pH - eU \quad (12)$$

$$\Delta G_4 = G(*) + G(O_2) + 0.5G(H_2) - G(OOH^*) - 0.059 \times pH - eU \quad (13)$$

OER-II⁴⁻⁸:



$$\Delta G_1 = G(OH^*) + 0.5G(H_2) - G(*) - G(H_2O) - 0.059 \times pH - eU \quad (20)$$

$$\Delta G_2 = G(O^*) + 0.5G(H_2) - G(OH^*) - 0.059 \times pH - eU \quad (21)$$

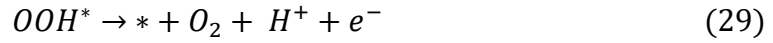
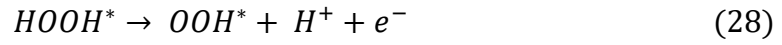
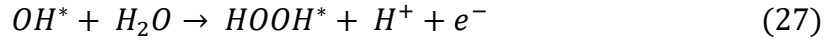
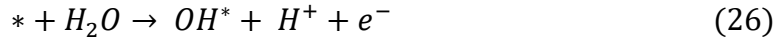
$$\Delta G_3 = G(O^*OH^*) + 0.5G(H_2) - G(O^*) - G(H_2O) - 0.059 \times pH - eU \quad (22)$$

$$\Delta G_4 = G(O^*O^*) + 0.5G(H_2) - G(O^*OH^*) - 0.059 \times pH - eU \quad (23)$$

$$\Delta G_5 = G(OO^*) - G(O^*O^*) \quad (24)$$

$$\Delta G_6 = G(*) + G(O_2) - G(OO^*) \quad (25)$$

OER-III^{6-7,9}:



$$\Delta G_1 = G(OH^*) + 0.5G(H_2) - G(*) - G(H_2O) - 0.059 \times pH - eU \quad (30)$$

$$\Delta G_2 = G(HOOH^*) + 0.5G(H_2) - G(OH^*) - G(H_2O) - 0.059 \times pH - eU \quad (31)$$

$$\Delta G_3 = G(OOH^*) + 0.5G(H_2) - G(HOOH^*) - 0.059 \times pH - eU \quad (32)$$

$$\Delta G_4 = G(*) + G(O_2) + 0.5G(H_2) - G(OOH^*) - 0.059 \times pH - eU \quad (33)$$

where * represents the active adsorption sites on the SnS₂/β-As heterostructure, and H*, OH*, O*, OOH*, O*OH*, O*O*, OO*, HOOH* represent the adsorption states during the redox process, respectively.

The solar-to-hydrogen (STH) efficiency

The solar-to-hydrogen (STH) efficiency is evaluated in the entire solar spectrum. The efficiency of light absorption is defined as¹⁰:

$$\eta_{abs} = \frac{\int_{E_g}^{\infty} p(h\omega)d(h\omega)}{\int_0^{\infty} p(h\omega)d(h\omega)} \quad (34)$$

where E_g is the bandgap of materials and $p(h\omega)$ is the AM1.5G solar

energy flux at the photon energy $h\omega$. The efficiency of carrier utilization is defined as:

$$\eta_{cu} = \frac{\Delta G \int_E^{\infty} \frac{p(h\omega)}{h\omega} d(h\omega)}{\int_{E_g}^{\infty} p(h\omega) d(h\omega)} \quad (35)$$

$$E = \begin{cases} E_g, (\chi(H_2) \geq 0.2, \chi(O_2) \geq 0.6) \\ E_g + 0.2 - \chi(H_2), (\chi(H_2) < 0.2, \chi(O_2) \geq 0.6) \\ E_g + 0.6 - \chi(O_2), (\chi(H_2) \geq 0.2, \chi(O_2) < 0.6) \\ E_g + 0.8 - \chi(H_2) - \chi(O_2), (\chi(H_2) < 0.2, \chi(O_2) < 0.6) \end{cases} \quad (36)$$

here ΔG is the water decomposition potential difference of 1.23 eV, and E is the photon energy that can actually be used for water splitting. The potential difference between the CBM-(β -As) and redox potential of H^+/H_2 ($\chi(H_2)$) is 0.81 eV, while the potential difference between the VBM-(SnS₂) and redox potential of H_2O/O_2 ($\chi(O_2)$) is 1.77 eV at pH = 0, respectively¹¹.

Therefore, the STH efficiency is defined as:

$$\eta_{STH} = \eta_{abs} \times \eta_{cu} \quad (37)$$

Spectral absorption

The interaction between photons and electrons in semiconductors can be understood as time-varying perturbations of ground-state electrons¹². Interband excited state transitions can induce common spectra of occupied and unoccupied states, and their optical properties are mainly determined by dielectric function ϵ ¹³. The imaginary part ϵ_2 can be estimated by the momentum matrix element between the occupied and unoccupied wave

functions, while the real part ε_1 can be obtained from ε_2 by Kramers-Kronig transformation¹⁴.

$$\varepsilon_2 = \frac{2e^2\pi}{\Omega\varepsilon_0} \sum_{k,v,c} |\langle \psi_k^c | \mathbf{u} \cdot \mathbf{r} | \psi_k^v \rangle|^2 \delta(E_k^c - E_k^v - E) \quad (38)$$

$$\varepsilon_1 = 1 + \frac{2}{\pi} p \int_0^\infty \frac{\omega' \varepsilon_2(\omega')}{\omega'^2 - \omega^2} d\omega' \quad (39)$$

where Ω , ω , v , and c are the unit-cell volume, photon frequency, valence bands, and conduction bands, respectively. \mathbf{u} and \mathbf{r} respectively represent the polarization vector of the incident electric field and the radius of the electron vector. The optical absorption coefficient $\alpha(\omega)$ of SnS₂, β -As, and SnS₂/ β -As heterostructure can then be calculated from ε_1 and ε_2 ¹⁵.

$$\alpha(\omega) = \sqrt{2}\omega \left[\sqrt{\varepsilon_1(\omega)^2 + \varepsilon_2(\omega)^2} - \varepsilon_1(\omega) \right]^{1/2} \quad (40)$$

Three SnS₂/ β -As heterostructure configurations

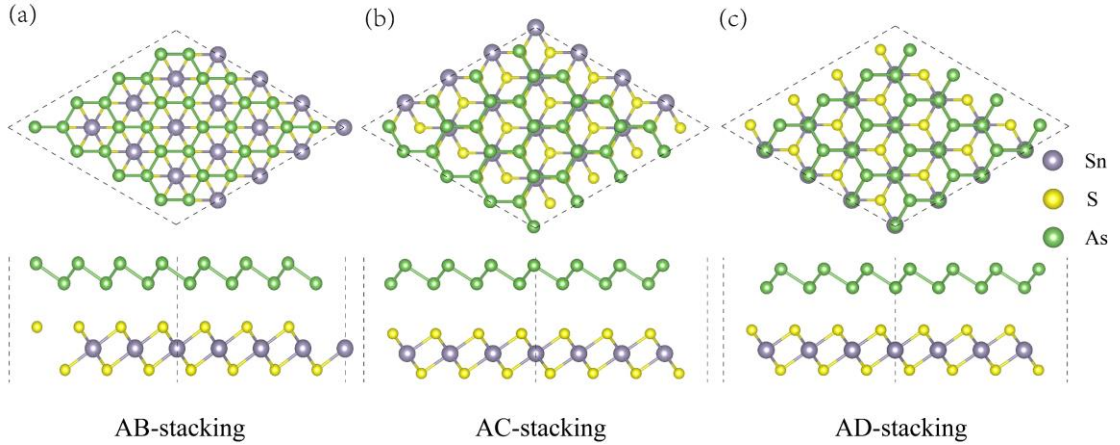


Figure S1 Top (upper panel) and side (lower panel) views of SnS₂/ β -As heterostructures with (a) AB-stacking, (b) AC-stacking and (c) AD-stacking.

Work function

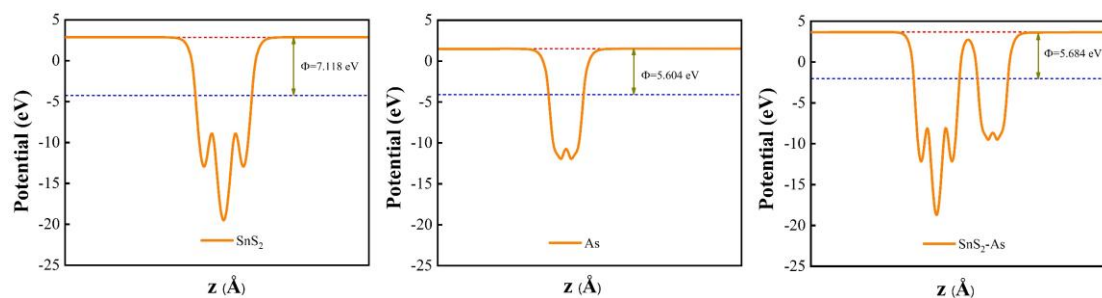


Figure S2 Work functions of SnS₂, β -As and SnS₂/ β -As nanosheets using the HSE06 hybrid functional method; the red and blue lines represent the vacuum and Fermi levels, respectively.

Water adsorption

By adsorbing a water molecule at different sites, the following four adsorption configurations are obtained after optimization. It can be seen that there is only one adsorption site for the water molecule on the surface of the β -As layer with an adsorption energy of -0.189 eV (Figure S3a). While there are two adsorption sites in the SnS₂ layer, namely the top of the S atom and Sn atom (Figure S3c,d) in the six-membered ring with adsorption energy of -0.164 and -0.162 eV, respectively. In addition, the water molecule has an adsorption energy of 0.685 eV between the β -As layer and the SnS₂ layer (Figure S3b). Because the adsorption energy on both layers is negative and the adsorption energy between layers is positive, it means that water molecules can be stably adsorbed on the surface of the SnS₂/ β -As heterostructure and participate in the decomposition reaction of water

but cannot occur between layers.

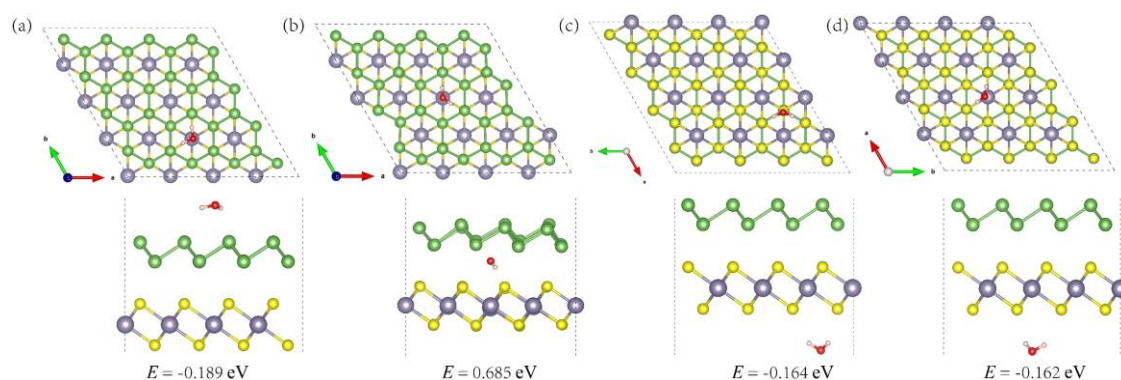


Figure S3 Adsorption of water molecules at different sites in the $\text{SnS}_2/\beta\text{-As}$ heterostructure, (a) six-membered ring center on the surface of the $\beta\text{-As}$ layer, (b) between the $\beta\text{-As}$ layer and the SnS_2 layer, (c) above the S atom in the six-membered ring center on the surface of the SnS_2 layer, and (d) above the Sn atom in the six-membered ring center on the surface of the SnS_2 layer.

HER and OER mechanisms

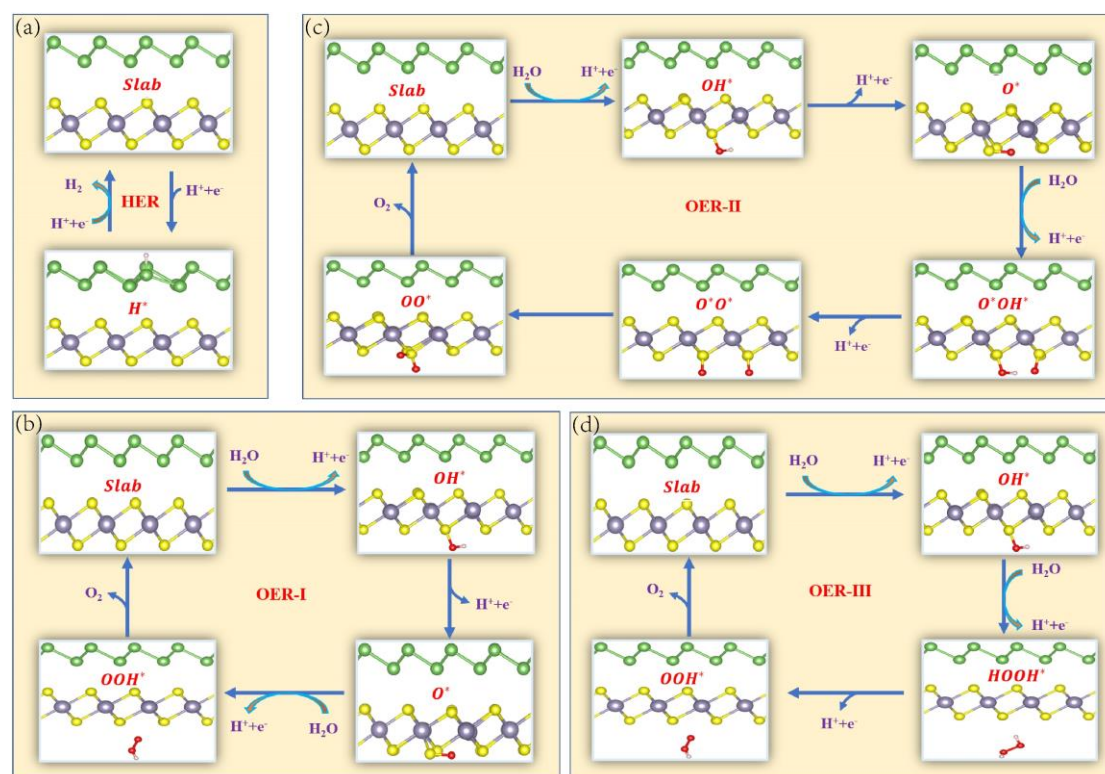


Figure S4 The intermediate states and adsorption sites of (a) HER, (b) OER-I, (c) OER-II and (d) OER-III in the $\text{SnS}_2/\beta\text{-As}$ heterostructure.

Spectral absorption

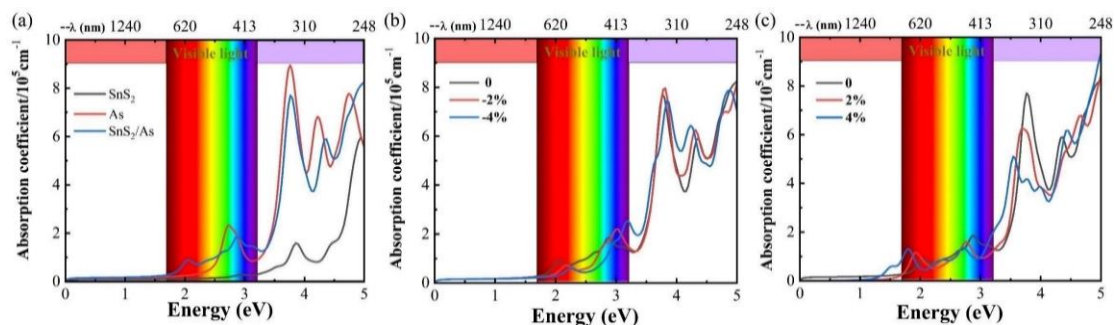


Figure S5 (a) spectral absorption of SnS₂, β -As and SnS₂/ β -As without strain; spectra absorption of (b) negative and (c) positive strains of the SnS₂/ β -As heterostructure.

Atomic coordinates

Table S1 Atomic fraction coordinates in SnS₂ and β -As nanosheets unit cells, and atomic fraction coordinates in SnS₂/ β -As heterostructure with AB-stacking.

	a	b	c
β -As - unit cell	0.367063	0.597467	0.25061
	0.700397	0.264133	0.19476
SnS ₂ - unit cell	0.000000	0.000000	0.500000
	0.333332	0.666668	0.564624
SnS ₂ / β -As heterostructure (2×2)	0.666668	0.333332	0.435376
	-0.00062	0.001908	0.415266
	0.499381	0.001908	0.415266
	-0.00062	0.501908	0.415266
	0.499381	0.501908	0.415266
	0.165987	0.335632	0.468391
	0.332711	0.168522	0.362254
	0.665987	0.335632	0.468391
0.832711	0.168522	0.362254	
0.165987	0.835632	0.468391	
0.332711	0.668522	0.362254	

	a	b	c
	0.665987	0.835632	0.468391
	0.832711	0.668522	0.362254
	0.164491	0.345702	0.625348
	0.331159	0.179036	0.576211
	0.664491	0.345702	0.625348
	0.831159	0.179036	0.576211
	0.164491	0.845702	0.625348
	0.331159	0.679036	0.576211
	0.664491	0.845702	0.625348
	0.831159	0.679036	0.576211

Table S2 The structural parameters, including lattice constant a ; the bond lengths of Sn-S (d_1), As-As (d_2); the distance between the layers (d); the bond angles of Sn-S-Sn (θ_1), S-Sn-S (θ_2), As-As-As (θ_3); the bandgap E_g (PBE/HSE06) of SnS₂/ β -As heterostructure with AB-stacking, AC-stacking, and AD-stacking; the binding energy E .

Structure	$a(\text{\AA})$	$d_1(\text{\AA})$	$d_2(\text{\AA})$	$d(\text{\AA})$	θ_1	θ_2	θ_3	$E_g(\text{eV})$	$E(\text{eV})$
AB	7.36	2.59	2.53	3.02	90.44°	89.54°	93.31°	0.31/0.89	-0.76
AC	7.36	2.59	2.53	3.73	90.37°	89.54°	93.25°	0.37/-	-0.46
AD	7.36	2.59	2.53	3.15	90.47°	89.52°	93.36°	0.18/-	-0.70

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